

Ultrafast Recovery Rectifier

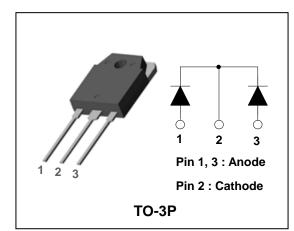
200V, 20A ULTRAFAST DUAL RECTIFIERS

Features

- Low forward voltage drop and leakage current
- Ultrafast reverse recovery time (trr<25ns)
- Low power loss and high efficiency
- Dual common cathode rectifier construction
- Full lead (Pb)-free and RoHS compliant device

Applications

- Switching power supply
- Power inverters
- Free-wheeling diode
- Power conversion system
- Motor drives



Product Characteristics

I _{F(AV)}	2 X 10A		
V _{RRM}	200V		
V_{FM} at 125 $^\circ\!$	0.88V		
t _{rr}	25ns		

Description

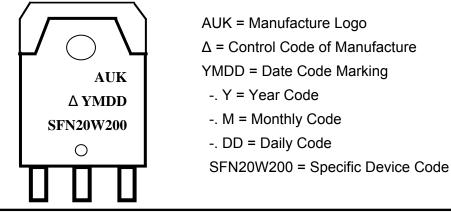
The SFN20W200CI is an ultrafast rectifier. It has a low forward voltage drop and reverse recovery time (trr<25ns). The planar structure and the platinum doper life time control guarantee the best overall performance, ruggedness and reliability characteristics.

The device is intended for use as a free wheeling, clamping rectifier in a variety of switching power supplies and other power switching applications.

Ordering Information

Device	Marking Code	Package	Packaging
SFN20W200CI	SFN20W200	TO-3P	Tube

Marking Information



Absolute Maximum Ratings (Limiting Values)

Characteristic		Symbol	Value	Unit
Maximum repetitive reverse voltage Maximum working peak reverse voltage Maximum DC blocking voltage		V _{RRM} V _{RWM} V _R	200	V
Maximum average forward restified surrent	per diode	I _{F(AV)}	10	A
Maximum average forward rectified current	total device		20	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load per diode		I _{FSM}	120	А
Storage temperature range		T _{stg}	-45 to +150	°C
Maximum operating junction temperature		Tj	150	U

Thermal Characteristics

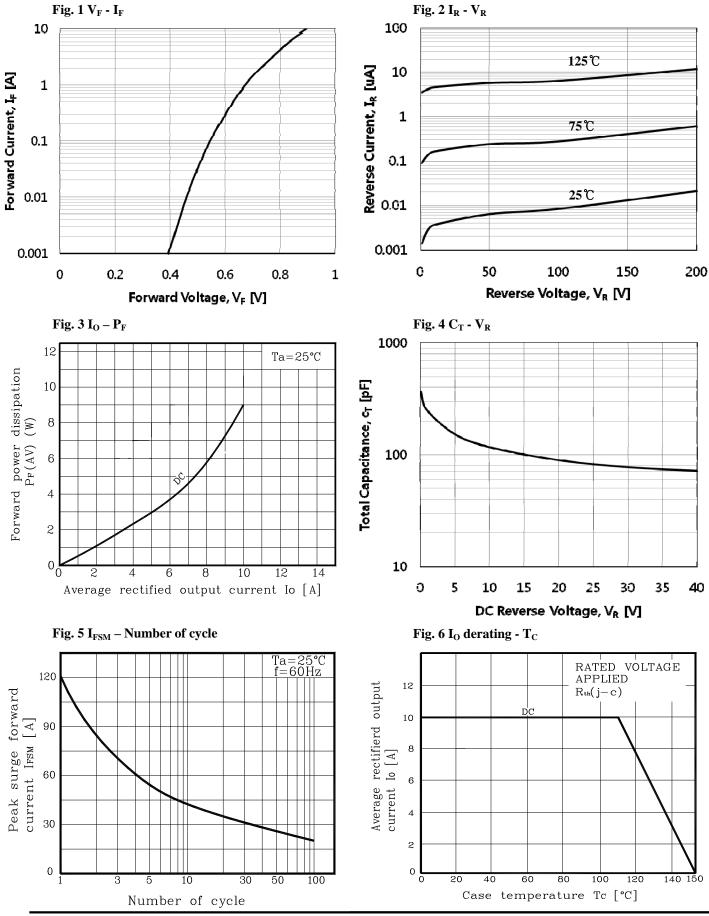
Characteristic		Symbol	Value	Unit	
Maximum thermal registence junction to acco	per diode	Р	2.5	°C/W	
Maximum thermal resistance junction to case	total device	R _{th(j-c)}	2.0	0700	

Electrical Characteristics (Per Diode)

Characteristic	Symbol	Test Condition		Min.	Тур.	Max.	Unit
Peak forward voltage drop	$V_{FM}^{(1)}$ $I_{FM} = 10A$	V ⁽¹⁾ L = 100	T j =25 ℃	-	-	0.98	V
Feak lotward voltage drop		T _j =125℃	-	-	0.88	v	
Reverse leakage current	$I_{\rm RM}^{(2)}$	V _R = V _{RRM}		-	-	10	uA
Reverse recovery time	t _{rr}	I _F = 1A, di/dt =-100 A/us		-	-	25	ns
Junction capacitance	C _j	$V_R = 5V_{DC}$, f=1MHz		-	150	-	pF

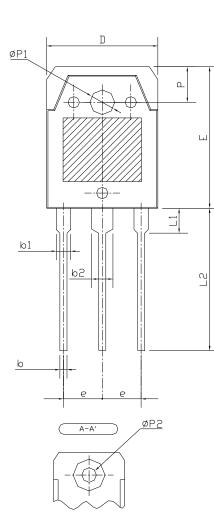
Note : (1) Pulse test : t_P \leq 380us, Duty cycle \leq 2%

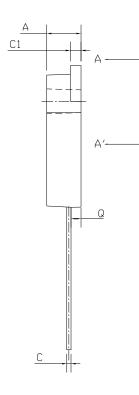
(2) Pulse test : $t_P \leq 20ms$, Duty cycle $\leq 2\%$



Rating and Characteristic Curves (Per Diode)

SYMBOL	MIN	NDM	MAX	
A	4.60	4.80	5.00	
b	0.80	1.00	1.20	
b1	1.80	2.00	2.20	
b2	2.80	3.00	3.20	
С	0.55	0.60	0.75	
C1	1.45	1.50	1.65	
D	15.40	15.60	15.80	
E	19.70	19.90	20.10	
e	5.15	5.45	5.75	
L1	3.30	3.50	3.70	
L2	19.80	20.00	20.20	
P	4.80	5.00	5.20	
ØP1	3.30	3.40	3.50	
ØP2	(3.20)			
Q	1.20	1.40	1.60	





Package Outline Dimension (Unit: mm)

SFN20W200CI

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